## Phase Control Thyristors (Hockey PUK Version), 1473 A



| PRIMARY CHARACTERISTICS |  |
| :---: | :---: |
| $\mathrm{I}_{\mathrm{T}(\mathrm{AV}}$ | 1473 A |
| $\mathrm{~V}_{\mathrm{DRM}} \mathrm{V}_{\mathrm{RRM}}$ | $1200 \mathrm{~V}, 1400 \mathrm{~V}, 1600 \mathrm{~V}, 1800 \mathrm{~V}$, <br> $2000 \mathrm{~V}, 2200 \mathrm{~V}, 2400 \mathrm{~V}$ |
| $\mathrm{~V}_{\mathrm{TM}}$ | 1.80 V |
| $\mathrm{I}_{\mathrm{GT}}$ | 100 mA |
| $\mathrm{~T}_{\mathrm{J}}$ | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| Package | $\mathrm{K}-\mathrm{PUK}(\mathrm{A}-24)$ |
| Circuit configuration | Single SCR |

## FEATURES

- Center amplifying gate
- Metal case with ceramic insulator
- International standard case K-PUK (A-24)
- High profile hockey PUK
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


## TYPICAL APPLICATIONS

- DC motor controls
- Controlled DC power supplies
- AC controllers

MAJOR RATINGS AND CHARACTERISTICS

| PARAMETER | TEST CONDITIONS | VALUES | UNITS |
| :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\mathrm{T}(\mathrm{AV})}$ |  | 1473 | A |
|  | $\mathrm{T}_{\text {hs }}$ | 55 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{I}_{\text {(RMS }}$ |  | 2913 | A |
|  | $\mathrm{T}_{\text {hs }}$ | 25 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{I}_{\text {TSM }}$ | 50 Hz | 20.0 | A |
|  | 60 Hz | 21.2 |  |
| $1^{2} \mathrm{t}$ | 50 Hz | 2000 | $\mathrm{kA}^{2} \mathrm{~s}$ |
|  | 60 Hz | 1865 |  |
| $\mathrm{I}^{2} \mathrm{~V} \mathrm{t}$ |  | 20000 | $\mathrm{kA}^{2} \sqrt{ } \mathrm{~s}$ |
| $\mathrm{V}_{\text {DRM }} / \mathrm{V}_{\text {RRM }}$ | Range | 1200 to 2400 | V |
| $\mathrm{t}_{\mathrm{q}}$ | Typical | 300 | $\mu \mathrm{s}$ |
| $\mathrm{T}_{J}$ | Range | -40 to +125 | ${ }^{\circ} \mathrm{C}$ |

## ELECTRICAL SPECIFICATIONS

| VOLTAGE RATINGS |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
| TYPE NUMBER | VOLTAGE CODE | VRRM, $^{\text {, MAXIMUM REPETITIVE PEAK }}$ REVERSE VOLTAGE V | $V_{\text {RSM }}$, MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V | $I_{\text {RRM }}$ MAXIMUM $\text { AT }_{J}=125^{\circ} \mathrm{C}$ $\mathrm{mA}$ |
| VS-ST1000C..K | 12 | 1200 | 1300 | 100 |
|  | 14 | 1400 | 1500 |  |
|  | 16 | 1600 | 1700 |  |
|  | 18 | 1800 | 1900 |  |
|  | 20 | 2000 | 2100 |  |
|  | 22 | 2200 | 2300 |  |
|  | 24 | 2400 | 2500 |  |

VS-ST1000C..K Series

## ABSOLUTE MAXIMUM RATINGS

| PARAMETER | SYMBOL | TEST CONDITIONS |  |  | VALUES | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Maximum average on-state current at heatsink temperature | $I_{\text {T(AV) }}$ | $180^{\circ}$ conduction, half sine wave Double side (single side) cooled |  |  | 1473 (630) | A |
|  |  |  |  |  | 55 (85) | ${ }^{\circ} \mathrm{C}$ |
| Maximum RMS on-state current | $\mathrm{I}_{\mathrm{T} \text { (RMS) }}$ | DC at $25^{\circ} \mathrm{C}$ heatsink temperature double side cooled |  |  | 6540 | A |
| Maximum peak, one-cycle, non-repetitive surge current | $I_{\text {TSM }}$ | $\mathrm{t}=10 \mathrm{~ms}$ | No voltage reapplied | Sinusoidal half wave, initial $T_{J}=T_{J}$ maximum | 20.0 | kA |
|  |  | $\mathrm{t}=8.3 \mathrm{~ms}$ |  |  | 21.2 |  |
|  |  | $\mathrm{t}=10 \mathrm{~ms}$ | 100 \% VRRM reapplied |  | 17.0 |  |
|  |  | $\mathrm{t}=8.3 \mathrm{~ms}$ |  |  | 18.1 |  |
| Maximum $\mathrm{l}^{2} \mathrm{t}$ for fusing | ${ }^{2} \mathrm{t}$ | $\mathrm{t}=10 \mathrm{~ms}$ | No voltage reapplied |  | 2000 | $\mathrm{kA}^{2} \mathrm{~s}$ |
|  |  | $\mathrm{t}=8.3 \mathrm{~ms}$ |  |  | 1865 |  |
|  |  | $\mathrm{t}=10 \mathrm{~ms}$ | 100 \% VRRM reapplied |  | 1445 |  |
|  |  | $\mathrm{t}=8.3 \mathrm{~ms}$ |  |  | 1360 |  |
| Maximum $I^{2} \sqrt{ }$ t for fusing | $\mathrm{I}^{2} \sqrt{\mathrm{t}}$ | $\mathrm{t}=0.1 \mathrm{~ms}$ to 10 ms , no voltage reapplied |  |  | 20000 | $\mathrm{kA}^{2} \sqrt{ } \mathrm{~s}$ |
| Low level value of threshold voltage | $\mathrm{V}_{\mathrm{T} \text { (TO) } 1}$ | (16.7 \% $\times \pi \times \mathrm{I}_{\mathrm{T}(\mathrm{AV})}<\mathrm{l}<\pi \times \mathrm{I}_{\mathrm{T}(\mathrm{AV})}$ ), $\mathrm{T}_{\mathrm{J}}=\mathrm{T}_{\mathrm{J}}$ maximum |  |  | 0.950 | V |
| High level value of threshold voltage | $\mathrm{V}_{\mathrm{T} \text { (TO)2 }}$ | $\left(\mathrm{l}>\pi \times \mathrm{I}_{\mathrm{T}(\mathrm{AV})}\right), \mathrm{T}_{\mathrm{J}}=\mathrm{T}_{\mathrm{J}}$ maximum |  |  | 1.024 |  |
| Low level value of on-state slope resistance | $\mathrm{r}_{\mathrm{t} 1}$ | (16.7 \% $\times \pi \times \mathrm{I}_{\mathrm{T}(\mathrm{AV})}<\mathrm{I}<\pi \times \mathrm{I}_{\mathrm{T}(\mathrm{AV})}$ ), $\mathrm{T}_{J}=\mathrm{T}_{J}$ maximum |  |  | 0.283 | $\mathrm{m} \Omega$ |
| High level value of on-state slope resistance | $\mathrm{r}_{\mathrm{t} 2}$ | $\left(\mathrm{l}>\pi \times \mathrm{I}_{\mathrm{T}(\mathrm{AV})}\right), \mathrm{T}_{J}=\mathrm{T}_{\mathrm{J}}$ maximum |  |  | 0.265 |  |
| Maximum on-state voltage drop | $\mathrm{V}_{\text {TM }}$ | $\mathrm{I}_{\mathrm{pk}}=3000 \mathrm{~A}, \mathrm{~T}_{J}=125^{\circ} \mathrm{C}, \mathrm{t}_{\mathrm{p}}=10 \mathrm{~ms}$ sine pulse |  |  | 1.80 | V |
| Maximum holding current | $\mathrm{I}_{\mathrm{H}}$ | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$, anode supply 12 V resistive load |  |  | 600 | mA |
| Typical latching current | $\mathrm{I}_{\mathrm{L}}$ |  |  |  | 1000 |  |


| SWITCHING |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| Maximum non-repetitive rate of rise of turned-on current | dl/dt | Gate drive $20 \mathrm{~V}, 20 \Omega, \mathrm{t}_{\mathrm{r}} \leq 1 \mu \mathrm{~s}$ $\mathrm{T}_{J}=\mathrm{T}_{J}$ maximum, anode voltage $\leq 80 \% \mathrm{~V}_{\text {DRM }}$ | 1000 | A/ $\mu \mathrm{s}$ |
| Typical delay time | $\mathrm{t}_{\text {d }}$ | Gate current $1 \mathrm{~A}, \mathrm{dl}_{\mathrm{g}} / \mathrm{dt}=1 \mathrm{~A} / \mu \mathrm{s}$ $V_{d}=0.67 \% V_{D R M}, T_{J}=25^{\circ} \mathrm{C}$ | 1.9 |  |
| Typical turn-off time | $\mathrm{t}_{\text {q }}$ | $\mathrm{I}_{\mathrm{TM}}=550 \mathrm{~A}, \mathrm{~T}_{\mathrm{J}}=\mathrm{T}_{\mathrm{J}}$ maximum, $\mathrm{dl} / \mathrm{dt}=40 \mathrm{~A} / \mu \mathrm{s}$, $\mathrm{V}_{\mathrm{R}}=50 \mathrm{~V}, \mathrm{dV} / \mathrm{dt}=20 \mathrm{~V} / \mu \mathrm{s}$, gate $0 \mathrm{~V} 100 \Omega, \mathrm{t}_{\mathrm{p}}=500 \mu \mathrm{~s}$ | 300 |  |


| BLOCKING | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| :--- | :---: | :---: | :---: | :---: |
| PARAMETER | $\mathrm{dV} / \mathrm{dt}$ | $\mathrm{T}_{J}=\mathrm{T}_{J}$ maximum linear to $80 \%$ rated $\mathrm{V}_{\text {DRM }}$ | 500 | $\mathrm{~V} / \mu \mathrm{s}$ |
| Maximum critical rate of rise of <br> off-state voltage | $\mathrm{I}_{\mathrm{RRM}}$, <br> IRM | $\mathrm{T}_{J}=\mathrm{T}_{J}$ maximum, rated $\mathrm{V}_{\text {DRM }} / \mathrm{V}_{\text {RRM }}$ applied | 100 | mA |
| Maximum peak reverse and <br> off-state leakage current |  |  |  |  |

VS-ST1000C..K Series

| TRIGGERING |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| PARAMETER | SYMBOL | TEST CONDITIONS |  | VALUES |  | UNITS |
|  |  |  |  | TYP. | MAX. |  |
| Maximum peak gate power | $\mathrm{P}_{\mathrm{GM}}$ | $\mathrm{T}_{J}=\mathrm{T}_{J}$ maximum, $\mathrm{t}_{\mathrm{p}} \leq 5 \mathrm{~ms}$ |  | 16 |  | W |
| Maximum peak average gate power | $\mathrm{P}_{\mathrm{G}(\mathrm{AV})}$ | $\mathrm{T}_{J}=\mathrm{T}_{J}$ maximum, $\mathrm{f}=50 \mathrm{~Hz}, \mathrm{~d} \%=50$ |  | 3 |  |  |
| Maximum peak positive gate current | $\mathrm{I}_{\mathrm{GM}}$ | $\mathrm{T}_{J}=\mathrm{T}_{J}$ maximum, $\mathrm{t}_{\mathrm{p}} \leq 5 \mathrm{~ms}$ |  | 3.0 |  | A |
| Maximum peak positive gate voltage | $+\mathrm{V}_{\mathrm{GM}}$ |  |  | 20 |  | V |
| Maximum peak negative gate voltage | $-V_{G M}$ |  |  | 5.0 |  |  |
| DC gate current required to trigger | $I_{\text {GT }}$ | $\mathrm{T}_{\mathrm{J}}=-40^{\circ} \mathrm{C}$ | Maximum required gate trigger/ current/voltage are the lowest value which will trigger all units 12 V anode to cathode applied | 200 | - | mA |
|  |  | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ |  | 100 | 200 |  |
|  |  | $\mathrm{T}_{\mathrm{J}}=125^{\circ} \mathrm{C}$ |  | 50 | - |  |
|  |  | $\mathrm{T}_{\mathrm{J}}=-40^{\circ} \mathrm{C}$ |  | 1.4 | - |  |
| DC gate voltage required to trigger | $\mathrm{V}_{\mathrm{GT}}$ | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ |  | 1.1 | 3.0 | v |
|  |  | $\mathrm{T}_{\mathrm{J}}=125^{\circ} \mathrm{C}$ |  | 0.9 | - |  |
| DC gate current not to trigger | $I_{\text {GD }}$ |  | Maximum gate current/voltage not to trigger is the maximum |  |  | mA |
| DC gate voltage not to trigger | $V_{G D}$ |  | unit with rated $V_{\text {DRM }}$ anode to cathode applied | 0.2 |  | V |

THERMAL AND MECHANICAL SPECIFICATIONS

| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| :---: | :---: | :---: | :---: | :---: |
| Maximum operating temperature range | $\mathrm{T}_{\mathrm{J}}$ |  | -40 to +125 | ${ }^{\circ} \mathrm{C}$ |
| Maximum storage temperature range | $\mathrm{T}_{\text {Stg }}$ |  | -40 to +150 |  |
| Maximum thermal resistance, | $\mathrm{R}_{\text {thJ }}$ hs | DC operation single side cooled | 0.042 | K/W |
| junction to heatsink |  | DC operation double side cooled | 0.021 |  |
| Maximum thermal resistance, case to heatsink | $\mathrm{R}_{\text {thC-hs }}$ | DC operation single side cooled | 0.006 |  |
|  |  | DC operation double side cooled | 0.003 |  |
| Mounting force, $\pm 10$ \% |  |  | $\begin{aligned} & 24500 \\ & (2500) \\ & \hline \end{aligned}$ | $\begin{gathered} \mathrm{N} \\ (\mathrm{~kg}) \end{gathered}$ |
| Approximate weight |  |  | 425 | 9 |
| Case style |  | See dimensions - link at the end of datasheet | K-PUK (A-24) |  |

## $\Delta \mathbf{R}_{\text {thJc }}$ CONDUCTION

| CONDUCTION ANGLE | SINUSOIDAL CONDUCTION |  | RECTANGULAR CONDUCTION |  | TEST CONDITIONS | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | SINGLE SIDE | DOUBLE SIDE | SINGLE SIDE | DOUBLE SIDE |  |  |
| $180^{\circ}$ | 0.003 | 0.003 | 0.002 | 0.002 | $\mathrm{T}_{J}=\mathrm{T}_{J}$ maximum | K/W |
| $120^{\circ}$ | 0.004 | 0.004 | 0.004 | 0.004 |  |  |
| $90^{\circ}$ | 0.005 | 0.005 | 0.005 | 0.005 |  |  |
| $60^{\circ}$ | 0.007 | 0.007 | 0.007 | 0.007 |  |  |
| $30^{\circ}$ | 0.012 | 0.012 | 0.012 | 0.012 |  |  |

## Note

- The table above shows the increment of thermal resistance $R_{\text {thJC }}$ when devices operate at different conduction angles than $D C$


Fig. 1 - Current Ratings Characteristics


Fig. 2 - Current Ratings Characteristics


Fig. 3 - Current Ratings Characteristics


Fig. 4 - Current Ratings Characteristics


Fig. 5 - On-State Power Loss Characteristics


Fig. 6 - On-State Power Loss Characteristics


Number Of Equal Amplitude Half Cycle Current Pulses (N)
Fig. 7 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled


Fig. 9 - On-State Voltage Drop Characteristics


Fig. 10 - Thermal Impedance $Z_{\text {thJ-hs }}$ Characteristics


Fig. 11 - Gate Characteristics

## ORDERING INFORMATION TABLE



1 - Vishay Semiconductors product
2 - Thyristor
3 - Essential part number
$4 \quad-\quad 0=$ converter grade
$5 \quad-\quad$ C $=$ ceramic PUK
6 - Voltage code $\times 100=V_{\text {RRM }}$ (see Voltage Ratings table)
$7 \quad-\quad K=$ PUK case K-PUK (A-24)
$8 \quad-\quad 0=$ eyelet terminals (gate and auxiliary cathode unsoldered leads)
1 = fast-on terminals (gate and auxiliary cathode unsoldered leads)
2 = eyelet terminals (gate and auxiliary cathode soldered leads)
3 = fast-on terminals (gate and auxiliary cathode soldered leads)
$9-\quad$ Critical dV/dt: • none $=500 \mathrm{~V} / \mu \mathrm{s}$ (standard selection)

- $\mathrm{L}=1000 \mathrm{~V} / \mu \mathrm{s}$ (special selection)

| LINKS TO RELATED DOCUMENTS |  |
| :--- | :---: |
| Dimensions | www.vishay.com/doc?95081 |

## K-PUK (A-24)

DIMENSIONS in millimeters (inches)
Creepage distance: 28.88 (1.137) minimum Strike distance: 17.99 (0.708) minimum


> Note:
> A = Anode
> C = Cathode
> G = Gate


Quote between upper and lower pole pieces has to be considered after application of mounting force (see thermal and mechanical specification)

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TT61N08KOF TD251N18KOF TD430N22KOF TT162N08KOF T2001N34TOF T901N35TOF T1080N02TOF T360N22TOF
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